

LM4040

Precision micropower shunt voltage references

Description

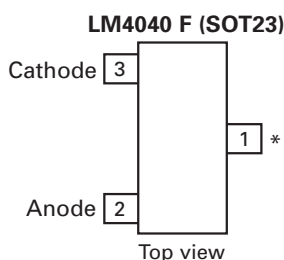
The LM4040 is a family of bandgap circuits designed to achieve precision micro-power voltage references of 2.5V, 3.0V and 5.0V. The devices are available in 0.2% B-grade, 0.5% C-grade and 1% D-grade initial tolerances.

They are available in small outline SOT23 and SC75 surface mount package which are ideal for applications where space saving is important.

Features

- Small packages: SOT23 & SC75
- No output capacitor required
- Output voltage tolerance
 - LM4040B $\pm 0.2\%$ at 25°C
 - LM4040C $\pm 0.5\%$ at 25°C
 - LM4040D $\pm 1\%$ at 25°C
- Low output noise
(10Hz to 10kHz)..... $45\mu\text{V}_{\text{RMS}}$
- Wide operating current range $60\mu\text{A}$ to 15mA
- Extended temperature range -40°C to $+125^{\circ}\text{C}$
- Low temperature coefficient $100\text{ ppm}/^{\circ}\text{C}$ (max)

Pinout information



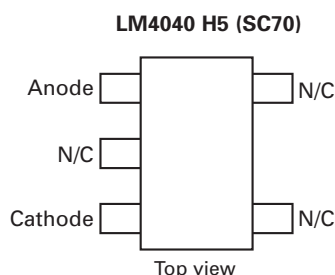
* Pin 1 must be left floating or connected to pin 2

Excellent performance is maintained over the $60\mu\text{A}$ to 15mA operating current range with a typical temperature coefficient of only $20\text{ppm}/^{\circ}\text{C}$. The device has been designed to be highly tolerant of capacitive loads so maintaining excellent stability.

This device offers a pin for pin compatible alternative to the LM4040 voltage reference. The LM4040 is also available with AEC-Q100 approval; see LM4040Q datasheet

Applications

- Battery powered equipment
- Precision power supplies
- Portable instrumentation
- Portable communications devices
- Notebook and palmtop computers
- Data acquisition systems



* Pin 1 must be left floating or connected to pin 2

Ordering information

25°C Tol	Voltage (V)	Order Code	Package	Part mark	Status	Reel Size	Tape Width	Quantity per reel
0.2%	2.5	LM4040B25FTA	SOT23	R2B	Active	7", 180mm	8mm	3000
		LM4040B25H5TA	SC75	R2B	Active	7", 180mm	8mm	3000
	3.0	LM4040B30FTA	SOT23	R3B	Active	7", 180mm	8mm	3000
		LM4040B30H5TA	SC75	R3B	Active	7", 180mm	8mm	3000
	5.0	LM4040B50FTA	SOT23	R5B	Active	7", 180mm	8mm	3000
		LM4040B50H5TA	SC75	R5B	Active	7", 180mm	8mm	3000
0.5%	2.5	LM4040C25FTA	SOT23	R2C	Active	7", 180mm	8mm	3000
		LM4040C25H5TA	SC75	R2C	Active	7", 180mm	8mm	3000
	3.0	LM4040C30FTA	SOT23	R3C	Active	7", 180mm	8mm	3000
		LM4040C30H5TA	SC75	R3C	Active	7", 180mm	8mm	3000
	5.0	LM4040C50FTA	SOT23	R5C	Active	7", 180mm	8mm	3000
		LM4040C50H5TA	SC75	R5C	Active	7", 180mm	8mm	3000
1%	2.5	LM4040D25FTA	SOT23	R2D	Active	7", 180mm	8mm	3000
		LM4040D25H5TA	SC75	R2D	Active	7", 180mm	8mm	3000
	3.0	LM4040D30FTA	SOT23	R3D	Active	7", 180mm	8mm	3000
		LM4040D30H5TA	SC75	R3D	Active	7", 180mm	8mm	3000
	5.0	LM4040D50FTA	SOT23	R5D	Active	7", 180mm	8mm	3000
		LM4040D50H5TA	SC75	R5D	Active	7", 180mm	8mm	3000

Absolute maximum ratings

Continuous reverse current (I_R) 20mA

Continuous forward current (I_{REF}) 10mA

Operating junction temperature -40°C to 150°C

Storage temperature -55°C to 150°C

Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

Unless otherwise stated voltages specified are relative to the ANODE pin.

Package thermal data

Package	θ_{JA}	P_{DIS} $T_{amb} = 25^\circ\text{C}, T_J = 150^\circ\text{C}$
SOT23	380°C/W	330mW
SC75	380°C/W	330mW

Recommended operating conditions

	Min.	Max.	Units
Reverse current	0.06	15	mA
Operating ambient temperature range	-40	125	°C

LM4040 - 2.5

Electrical characteristics

Over recommended operating conditions, $T_{amb} = 25^{\circ}\text{C}$, unless otherwise stated.

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	$I_R = 100\mu\text{A}$	25°C	2.5				V
	Reverse breakdown voltage tolerance	$I_R = 100\mu\text{A}$	25°C		± 5	± 12	± 25	mV
			-40 to 85°C		± 21	± 29	± 49	
			-40 to 125°C		± 30	± 38	± 63	
I_{RMIN}	Minimum operating current		25°C	45	60	60	65	μA
			-40 to 85°C		65	65	70	
			-40 to 125°C		68	68	73	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	$I_R = 10\text{mA}$	-40 to 125°C	± 20				ppm/ $^{\circ}\text{C}$
		$I_R = 1\text{mA}$		± 15	100	± 100	± 150	
		$I_R = 100\mu\text{A}$		± 15				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R < 1\text{mA}$	25°C	0.3	0.8	0.8	1.0	mV
			-40 to 85°C		1.0	1.0	1.2	
			-40 to 125°C		1.0	1.0	1.2	
		$1\text{mA} < I_R < 15\text{mA}$	25°C	2.5	6.0	6.0	8.0	
			-40 to 85°C		8.0	8.0	10.0	
			-40 to 125°C		8.0	8.0	10.0	
Z_R	Dynamic output impedance	$I_R = 1\text{mA}$, $f = 120\text{Hz}$ $I_{AC} = 0.1I_R$		0.3	0.8	0.9	1.1	Ω
e_n	Noise voltage	$I_R = 100\mu\text{A}$ $10\text{Hz} < f < 10\text{kHz}$		35				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	$t = 1000\text{Hrs}$ $I_R = 100\mu\text{A}$		120				ppm
V_{HYST}	Thermal hysteresis	$\Delta T = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		0.08				%

LM4040 - 3.0

Electrical characteristics

Over recommended operating conditions, $T_{amb} = 25^{\circ}\text{C}$, unless otherwise stated

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	$I_R = 100\mu\text{A}$	25°C	3.0				V
	Reverse breakdown voltage tolerance	$I_R = 100\mu\text{A}$	25°C		± 6	± 15	± 30	mV
			-40 to 85°C		± 26	± 34	± 59	
			-40 to 125°C		TBD	± 45	± 75	
I_{RMIN}	Minimum operating current		25°C	47	62	62	67	μA
			-40 to 85°C		67	67	72	
			-40 to 125°C		70	70	75	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	$I_R = 10\text{mA}$	-40 to 125°C	± 20				ppm/ $^{\circ}\text{C}$
		$I_R = 1\text{mA}$		± 15	100	± 100	± 150	
		$I_R = 100\mu\text{A}$		± 15				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R < 1\text{mA}$	25°C	0.4	0.8	0.8	1.1	mV
			-40 to 85°C		1.1	1.1	1.3	
			-40 to 125°C		1.1	1.1	1.3	
		$1\text{mA} < I_R < 15\text{mA}$	25°C	2.7	6.0	6.0	8.0	
			-40 to 85°C		9.0	9.0	11.0	
			-40 to 125°C		9.0	9.0	11.0	
Z_R	Dynamic output impedance	$I_R = 1\text{mA}$, $f = 120\text{Hz}$ $I_{AC} = 0.1I_R$		0.4	0.9	0.9	1.2	Ω
e_n	Noise voltage	$I_R = 100\mu\text{A}$ $10\text{Hz} < f < 10\text{kHz}$		35				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	$t = 1000\text{Hrs}$ $I_R = 100\mu\text{A}$		120				ppm
V_{HYST}	Thermal hysteresis	$\Delta T = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		0.08				%

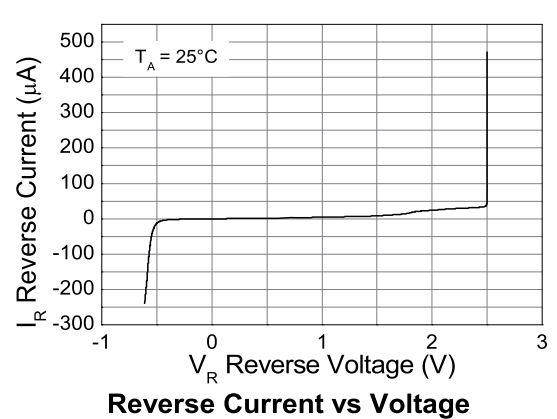
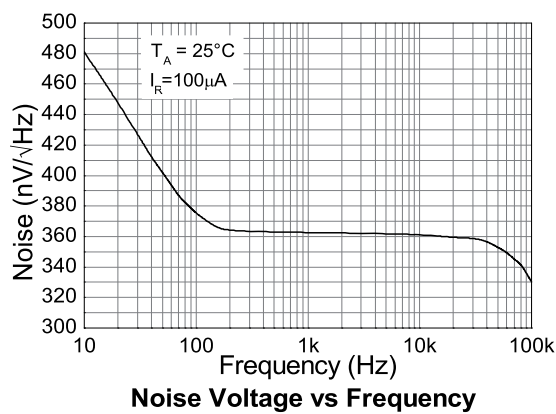
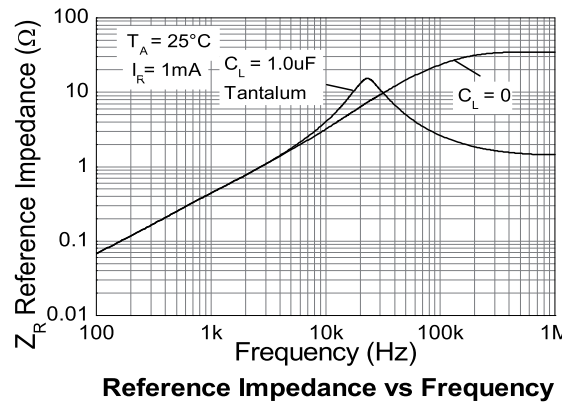
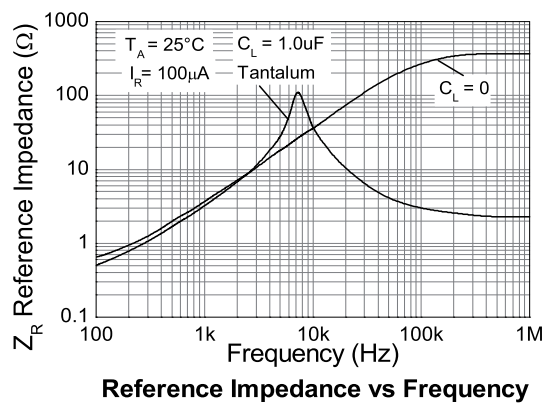
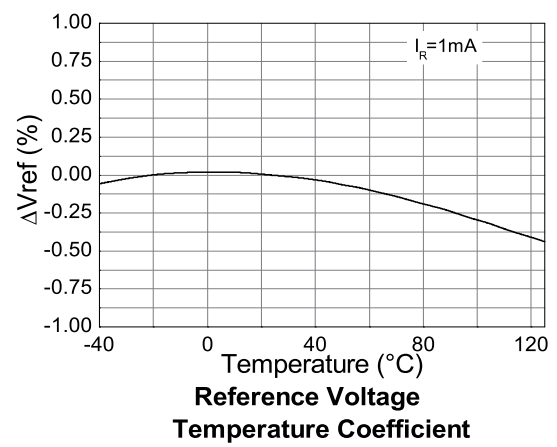
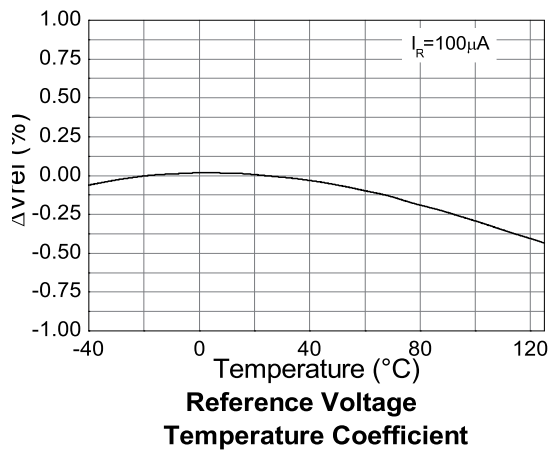
LM4040 - 5.0

Electrical characteristics

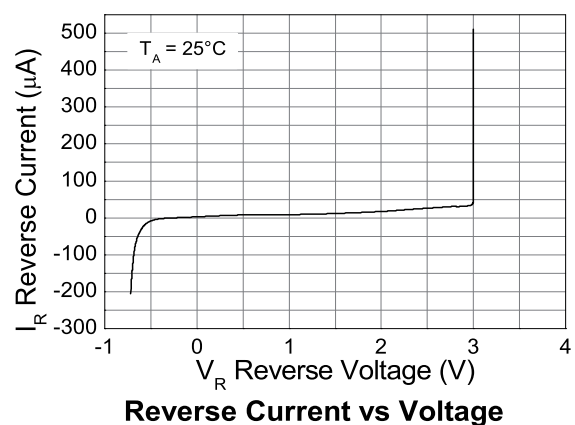
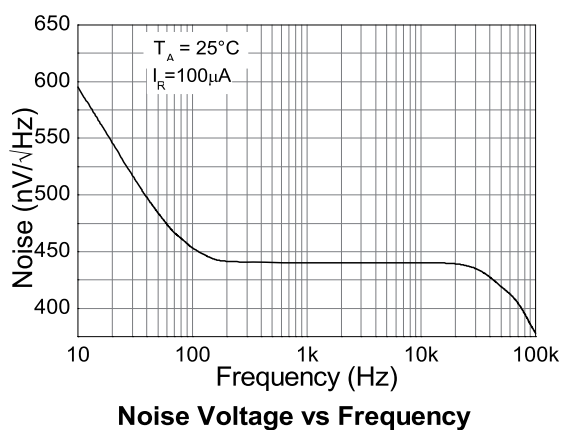
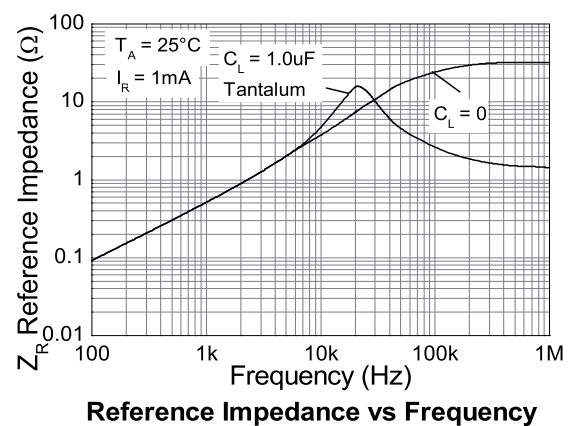
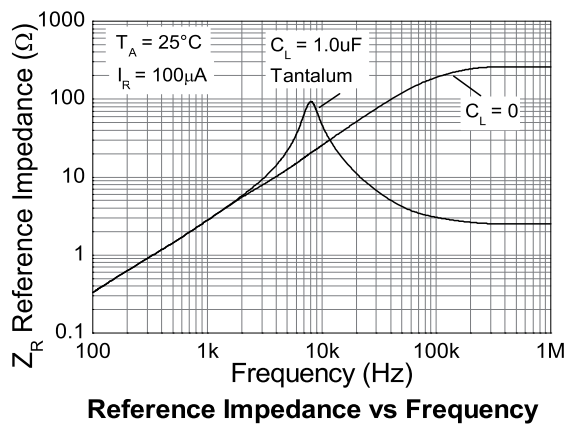
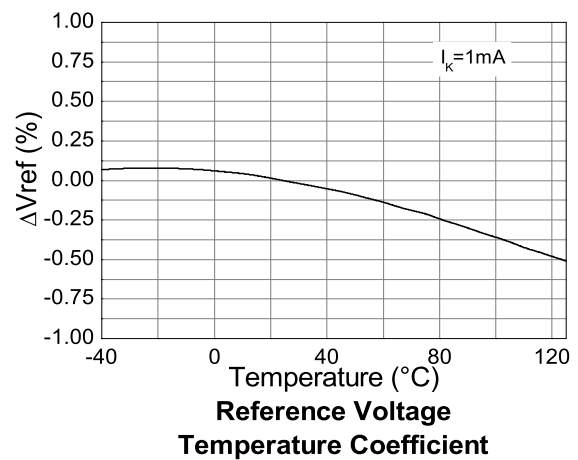
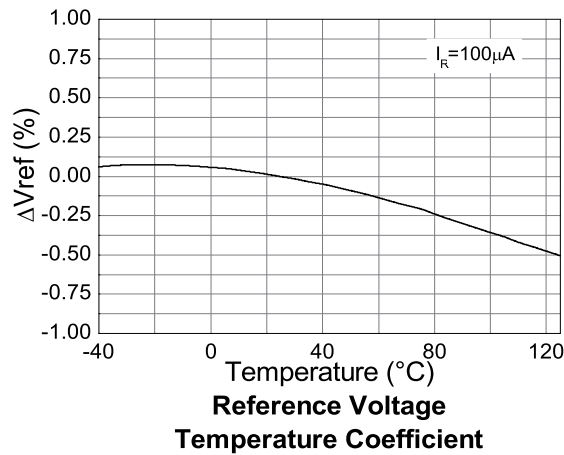
Over recommended operating conditions, $T_{amb} = 25^{\circ}\text{C}$, unless otherwise stated.

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	$I_R = 100\mu\text{A}$	25°C	5.0	5.0			V
	Reverse breakdown voltage tolerance	$I_R = 100\mu\text{A}$	25°C		± 10	± 25	± 50	mV
			-40 to 85°C		± 43	± 58	± 99	
			-40 to 125°C		± 60	± 75	± 125	
I_{RMIN}	Minimum operating current		25°C	54	74	74	79	μA
			-40 to 85°C		80	80	85	
			-40 to 125°C		83	83	88	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	$I_R = 10\text{mA}$	-40 to 125°C	± 30				ppm/ $^{\circ}\text{C}$
		$I_R = 1\text{mA}$		± 20	100	± 100	± 150	
		$I_R = 100\mu\text{A}$		± 20				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R < 1\text{mA}$	25°C	0.5	1.0	1.0	1.3	mV
			-40 to 85°C		1.4	1.4	1.8	
			-40 to 125°C		1.4	1.4	1.8	
		$1\text{mA} < I_R < 15\text{mA}$	25°C	3.5	8.0	8.0	10.0	
			-40 to 85°C		12.0	12.0	15.0	
			-40 to 125°C		12.0	12.0	15.0	
Z_R	Dynamic output impedance	$I_R = 1\text{mA}$, $f = 120\text{Hz}$ $I_{AC} = 0.1I_R$		0.5	1.1	1.1	1.5	Ω
e_n	Noise voltage	$I_R = 100\mu\text{A}$ $10\text{Hz} < f < 10\text{kHz}$		80				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	$t = 1000\text{Hrs}$ $I_R = 100\mu\text{A}$		120				ppm
V_{HYST}	Thermal hysteresis	$\Delta T = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		0.08				%

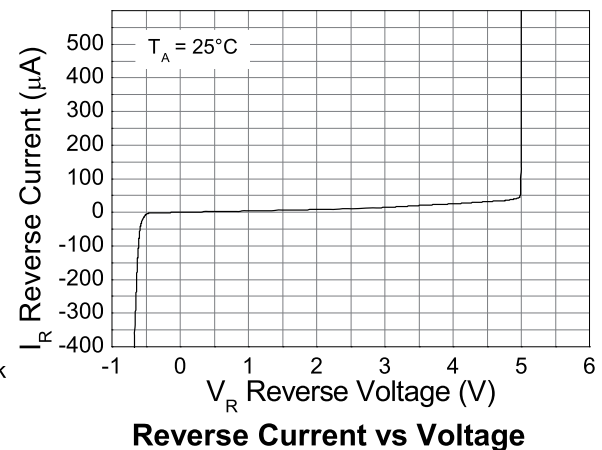
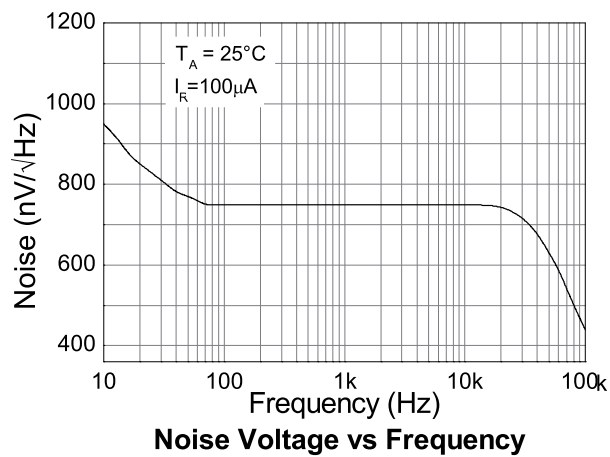
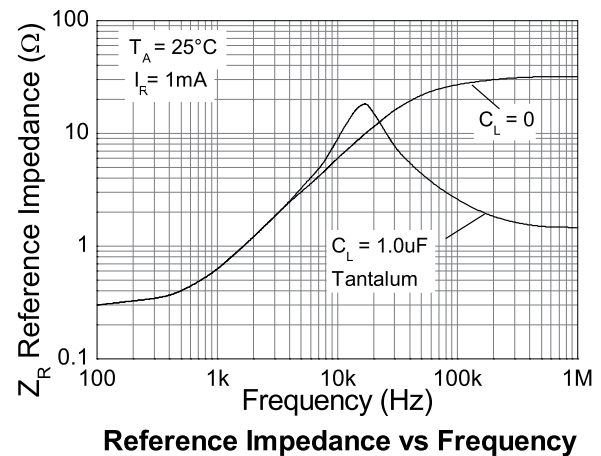
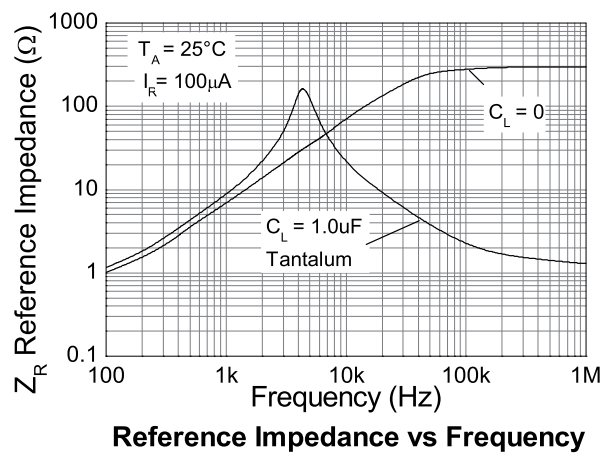
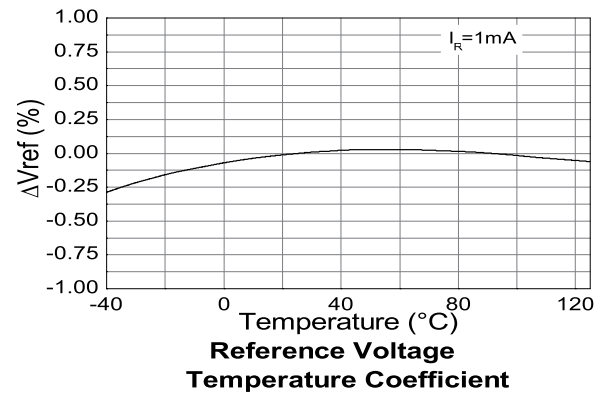
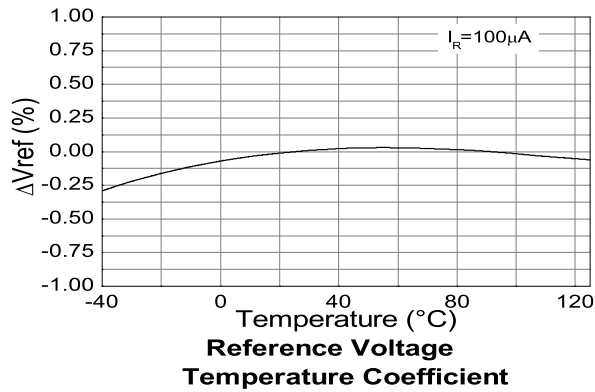
LM4040-2.5 Typical Characteristics



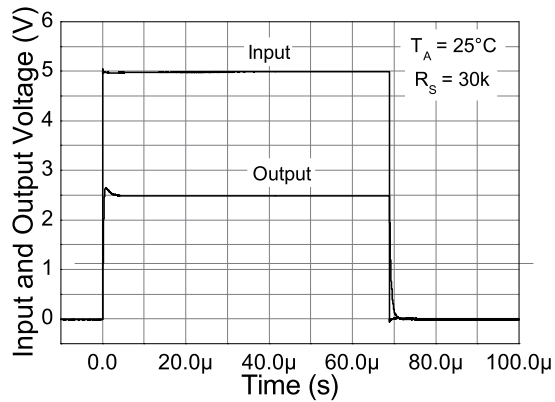
LM4040-3.0 Typical characteristics



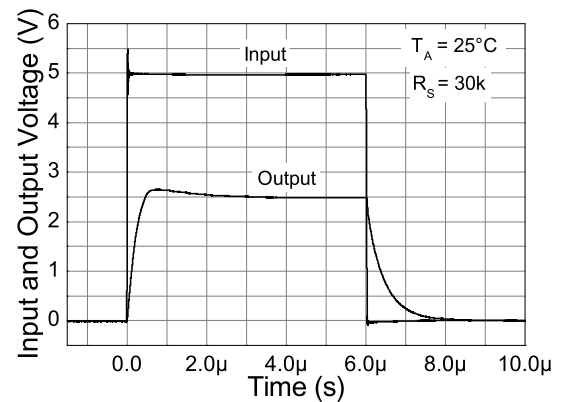
LM4040-5.0 Typical characteristics



LM4040 - 2.5, 3.0 and 5.0 Start up characteristics

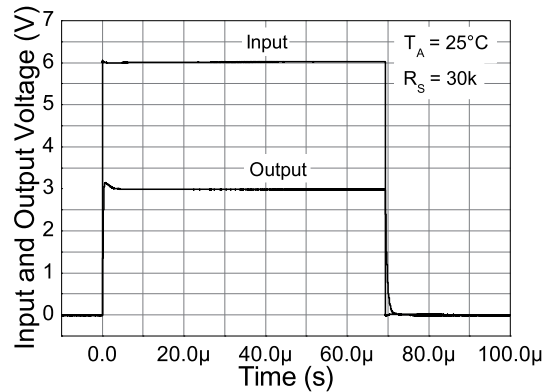


Long Pulse Response

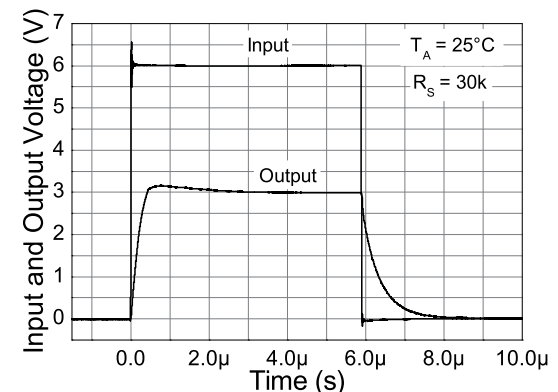


Short Pulse Response

LM4040-3.0

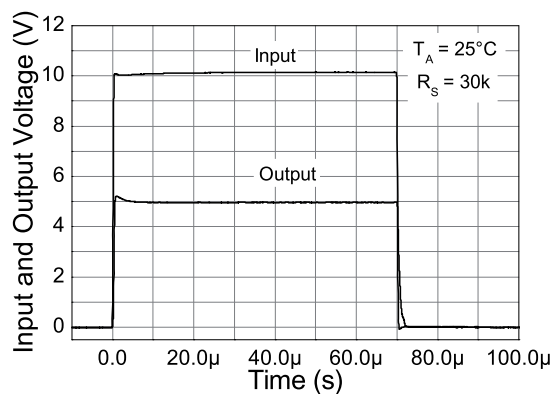


Long Pulse Response

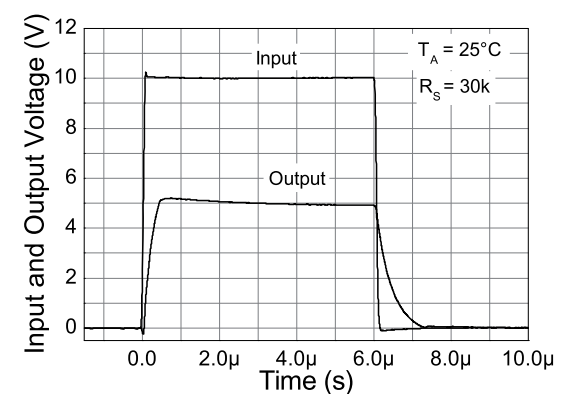


Short Pulse Response

LM4040-5.0

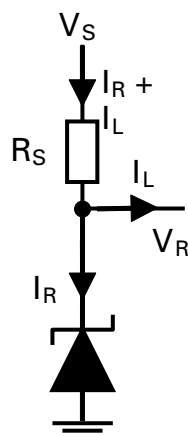


Long Pulse Response



Short Pulse Response

Application information



In a conventional shunt regulator application, an external series resistor (R_S) is connected between the supply voltage, V_S , and the LM4040

R_S determines the current that flows through the load (I_L) and the LM4040 (I_R). Since load current and supply voltage may vary, R_S should be small enough to supply at least the minimum acceptable I_R to the LM4040 even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its maximum and I_L is at its minimum, R_S should be large enough so that the current flowing through the LM4040 is less than 15 mA.

R_S is determined by the supply voltage, (V_S), the load and operating current, (I_L and I_R), and the LM4040's reverse breakdown voltage, V_R .

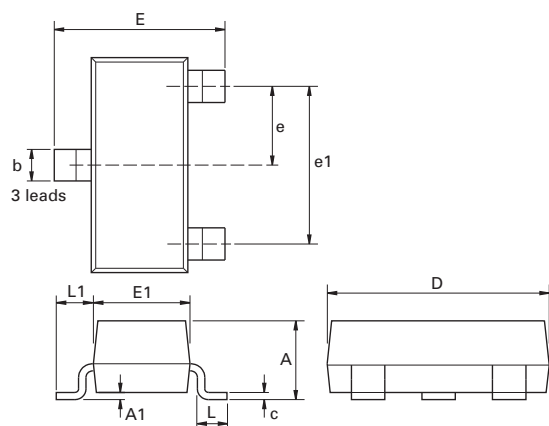
$$R_S = \frac{V_S - V_R}{I_L + I_R}$$

Printed circuit board layout considerations

LM4040s in the SOT23 package have the die attached to pin 1, which results in an electrical contact between pin 2 and pin 3. Therefore, pin 1 of the SOT-23 package must be left floating or connected to pin 2.

LM4040s in the SC75 package have the die attached to pin 2, which results in an electrical contact between pin 2 and pin 1. Therefore, pin 2 must be left floating or connected to pin1.

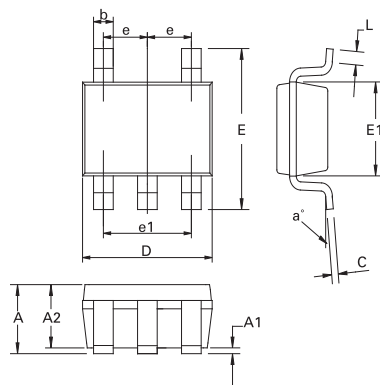
Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
C	0.085	0.120	0.003	0.008	L	0.25	0.62	0.018	0.024
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
e	0.95 NOM		0.0375 NOM		-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Package outline SC-70-5



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	0.80	1.10	0.0315	0.0433	E	2.10 BSC		0.0826 BSC	
A1	-	0.10	-	0.0039	E1	1.25 BSC		0.0492 BSC	
A2	0.80	1.00	0.0315	0.0394	e	0.65 BSC		0.0255 BSC	
b	0.15	0.30	0.006	0.0118	e1	1.30 BSC		0.0511 BSC	
C	0.08	0.25	0.0031	0.0098	L	0.26	0.46	0.0102	0.0181
D	2.00 BSC		0.0787 BSC		a°	0	8	0	8

Definitions

Product change

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1. are intended to implant into the body

or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labelling can be reasonably expected to result in significant injury to the user.

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ESD (Electrostatic discharge)

Semiconductor devices are susceptible to damage by ESD. Suitable precautions should be taken when handling and transporting devices. The possible damage to devices depends on the circumstances of the handling and transporting, and the nature of the device. The extent of damage can vary from immediate functional or parametric malfunction to degradation of function or performance in use over time. Devices suspected of being affected should be replaced.

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All Diodes Zetex components are compliant with the RoHS directive, and through this it is supporting its customers in their compliance with WEEE and ELV directives.

Product status key:

"Preview"	Future device intended for production at some point. Samples may be available
"Active"	Product status recommended for new designs
"Last time buy (LTB)"	Device will be discontinued and last time buy period and delivery is in effect
"Not recommended for new designs"	Device is still in production to support existing designs and production
"Obsolete"	Production has been discontinued

Datasheet status key:

"Draft version"	This term denotes a very early datasheet version and contains highly provisional information, which may change in any manner without notice.
"Provisional version"	This term denotes a pre-release datasheet. It provides a clear indication of anticipated performance. However, changes to the test conditions and specifications may occur, at any time and without notice.
"Issue"	This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.

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Zetex GmbH Kustermann-park Balanstraße 59 D-81541 München Germany Telefon: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 9 europe.sales@zetex.com	Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com	Diodes Zetex (Asia) Ltd 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com	Diodes Incorporated 15660 N. Dallas Parkway Suite 850, Dallas TX75248, USA www.diodes.com

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Данный компонент на территории Российской Федерации

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9